

FEATURES

- Micropower, 85 μA maximum supply current
- Wide power supply range (+2.2 V to ± 18 V)
- Easy to use
 - Gain set with one external resistor
 - Gain range 5 (no resistor) to 1000
- Higher performance than discrete designs
- Rail-to-rail output swing
- High accuracy dc performance
 - 0.03% typical gain accuracy ($G = +5$) (AD627A)
 - 10 ppm/ $^{\circ}\text{C}$ typical gain drift ($G = +5$)
 - 125 μV maximum input offset voltage (AD627B dual supply)
 - 200 μV maximum input offset voltage (AD627A dual supply)
 - 1 $\mu\text{V}/^{\circ}\text{C}$ maximum input offset voltage drift (AD627B)
 - 3 $\mu\text{V}/^{\circ}\text{C}$ maximum input offset voltage drift (AD627A)
 - 10 nA maximum input bias current
- Noise: 38 nV/ $\sqrt{\text{Hz}}$ RTI noise @ 1 kHz ($G = +100$)
- Excellent ac specifications
 - AD627A: 77 dB minimum CMRR ($G = +5$)
 - AD627B: 83 dB minimum CMRR ($G = +5$)
 - 80 kHz bandwidth ($G = +5$)
 - 135 μs settling time to 0.01% ($G = +5$, 5 V step)

APPLICATIONS

- 4 to 20 mA loop-powered applications
- Low power medical instrumentation—ECG, EEG
- Transducer interfacing
- Thermocouple amplifiers
- Industrial process controls
- Low power data acquisition
- Portable battery-powered instruments

GENERAL DESCRIPTION

The AD627 is an integrated, micropower instrumentation amplifier that delivers rail-to-rail output swing on single and dual (+2.2 V to ± 18 V) supplies. The AD627 provides excellent ac and dc specifications while operating at only 85 μA maximum.

The AD627 offers superior flexibility by allowing the user to set the gain of the device with a single external resistor while conforming to the 8-lead industry-standard pinout configuration. With no external resistor, the AD627 is configured for a gain of 5. With an external resistor, it can be set to a gain of up to 1000.

A wide supply voltage range (+2.2 V to ± 18 V) and micropower current consumption make the AD627 a perfect fit for a wide range of applications. Single-supply operation, low power consumption, and rail-to-rail output swing make the AD627

FUNCTIONAL BLOCK DIAGRAM

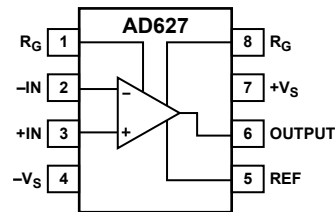


Figure 1. 8-Lead PDIP (N) and SOIC_N (R)

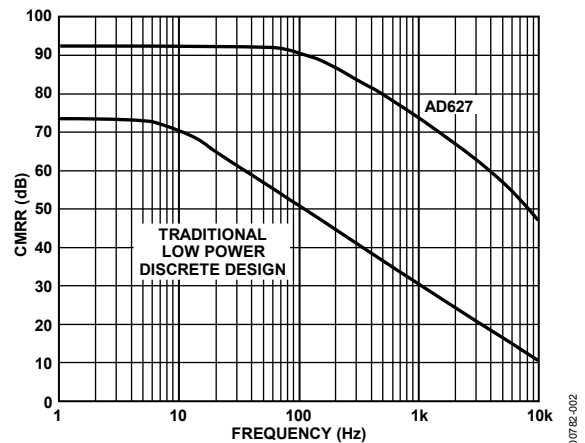


Figure 2. CMRR vs. Frequency, ± 5 V, Gain = +5

ideal for battery-powered applications. Its rail-to-rail output stage maximizes dynamic range when operating from low supply voltages. Dual-supply operation (± 15 V) and low power consumption make the AD627 ideal for industrial applications, including 4 to 20 mA loop-powered systems.

The AD627 does not compromise performance, unlike other micropower instrumentation amplifiers. Low voltage offset, offset drift, gain error, and gain drift minimize errors in the system. The AD627 also minimizes errors over frequency by providing excellent CMRR over frequency. Because the CMRR remains high up to 200 Hz, line noise and line harmonics are rejected.

The AD627 provides superior performance, uses less circuit board area, and costs less than micropower discrete designs.

Rev. D

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

SPECIFICATIONS

SINGLE SUPPLY

Typical @ 25°C single supply, $V_S = 3\text{ V}$ and 5 V , and $R_L = 20\text{ k}\Omega$, unless otherwise noted.

Table 1.

Parameter	Conditions	AD627A			AD627B			Unit
		Min	Typ	Max	Min	Typ	Max	
GAIN	$G = +5 + (200\text{ k}\Omega/R_G)$							
Gain Range		5		1000	5		1000	V/V
Gain Error ¹	$V_{OUT} = (-V_S) + 0.1$ to $(+V_S) - 0.15$							
G = +5			0.03	0.10		0.01	0.06	%
G = +10			0.15	0.35		0.10	0.25	%
G = +100			0.15	0.35		0.10	0.25	%
G = +1000			0.50	0.70		0.25	0.35	%
Nonlinearity								
G = +5			10	100		10	100	ppm
G = +100			20	100		20	100	ppm
Gain vs. Temperature¹								
G = +5			10	20		10	20	ppm/°C
G > +5			-75			-75		ppm/°C
VOLTAGE OFFSET								
Input Offset, V_{OSI} ²			50	250		25	150	μV
Over Temperature	$V_{CM} = V_{REF} = +V_S/2$			445			215	μV
Average TC			0.1	3		0.1	1	$\mu\text{V}/^\circ\text{C}$
Output Offset, V_{OSO}				1000			500	μV
Over Temperature				1650			1150	μV
Average TC			2.5	10		2.5	10	$\mu\text{V}/^\circ\text{C}$
Offset Referred to the Input vs. Supply (PSRR)								
G = +5		86	100		86	100		dB
G = +10		100	120		100	120		dB
G = +100		110	125		110	125		dB
G = +1000		110	125		110	125		dB
INPUT CURRENT								
Input Bias Current			3	10		3	10	nA
Over Temperature				15			15	nA
Average TC			20			20		pA/°C
Input Offset Current			0.3	1		0.3	1	nA
Over Temperature				2			2	nA
Average TC			1			1		pA/°C
INPUT								
Input Impedance								
Differential			20 2			20 2		$\text{G}\Omega \text{pF}$
Common-Mode			20 2			20 2		$\text{G}\Omega \text{pF}$
Input Voltage Range ³	$V_S = 2.2\text{ V}$ to 36 V	$(-V_S) - 0.1$		$(+V_S) - 1$	$(-V_S) - 0.1$		$(+V_S) - 1$	V
Common-Mode Rejection Ratio ³ DC to 60 Hz with 1 k Ω Source Imbalance	$V_{REF} = V_S/2$							
G = +5	$V_S = 3\text{ V}, V_{CM} = 0\text{ V}$ to 1.9 V	77	90		83	96		dB
G = +5	$V_S = 5\text{ V}, V_{CM} = 0\text{ V}$ to 3.7 V	77	90		83	96		dB
OUTPUT								
Output Swing	$R_L = 20\text{ k}\Omega$	$(-V_S) + 25$		$(+V_S) - 70$	$(-V_S) + 25$		$(+V_S) - 70$	mV
	$R_L = 100\text{ k}\Omega$	$(-V_S) + 7$		$(+V_S) - 25$	$(-V_S) + 7$		$(+V_S) - 25$	mV
Short-Circuit Current	Short circuit to ground		± 25			± 25		mA

AD627

Parameter	Conditions	AD627A			AD627B			Unit
		Min	Typ	Max	Min	Typ	Max	
DYNAMIC RESPONSE								
Small Signal -3 dB Bandwidth								
G = +5			80			80		kHz
G = +100			3			3		kHz
G = +1000			0.4			0.4		kHz
Slew Rate			+0.05/-0.07		+0.05/-0.07			V/ μ s
Settling Time to 0.01%	$V_S = 3$ V, 1.5 V output step							
G = +5			65			65		μ s
G = +100			290			290		μ s
Settling Time to 0.01%	$V_S = 5$ V, 2.5 V output step							
G = +5			85			85		μ s
G = +100			330			330		μ s
Overload Recovery	50% input overload		3			3		μ s

¹ Does not include effects of External Resistor R_G .

² See Table 8 for total RTI errors.

³ See the Using the AD627 section for more information on the input range, gain range, and common-mode range.

DUAL SUPPLY

Typical @ 25°C dual supply, $V_s = \pm 5\text{ V}$ and $\pm 15\text{ V}$, and $R_L = 20\text{ k}\Omega$, unless otherwise noted.

Table 2.

Parameter	Conditions	AD627A			AD627B			Unit
		Min	Typ	Max	Min	Typ	Max	
GAIN	$G = +5 + (200\text{ k}\Omega/R_G)$							
Gain Range		5		1000	5		1000	V/V
Gain Error ¹	$V_{OUT} = (-V_s) + 0.1$ to $(+V_s) - 0.15$							
G = +5			0.03	0.10		0.01	0.06	%
G = +10			0.15	0.35		0.10	0.25	%
G = +100			0.15	0.35		0.10	0.25	%
G = +1000			0.50	0.70		0.25	0.35	%
Nonlinearity								
G = +5	$V_s = \pm 5\text{ V}/\pm 15\text{ V}$		10/25	100		10/25	100	ppm
G = +100	$V_s = \pm 5\text{ V}/\pm 15\text{ V}$		10/15	100		10/15	100	ppm
Gain vs. Temperature¹								
G = +5			10	20		10	20	ppm/°C
G > +5			-75			-75		ppm/°C
VOLTAGE OFFSET	Total RTI error = $V_{OSI} + V_{OSO}/G$							
Input Offset, V_{OSI} ²			25	200		25	125	μV
Over Temperature	$V_{CM} = V_{REF} = 0\text{ V}$			395			190	μV
Average TC			0.1	3		0.1	1	$\mu\text{V}/^\circ\text{C}$
Output Offset, V_{OSO}				1000			500	μV
Over Temperature				1700			1100	μV
Average TC			2.5	10		2.5	10	$\mu\text{V}/^\circ\text{C}$
Offset Referred to the Input vs. Supply (PSRR)								
G = +5		86	100		86	100		dB
G = +10		100	120		100	120		dB
G = +100		110	125		110	125		dB
G = +1000		110	125		110	125		dB
INPUT CURRENT								
Input Bias Current			2	10		2	10	nA
Over Temperature				15			15	nA
Average TC			20			20		pA/°C
Input Offset Current			0.3	1		0.3	1	nA
Over Temperature				5			5	nA
Average TC			5			5		pA/°C
INPUT								
Input Impedance								
Differential				20 2			20 2	G Ω pF
Common Mode				20 2			20 2	G Ω pF
Input Voltage Range ³	$V_s = \pm 1.1\text{ V}$ to $\pm 18\text{ V}$	$(-V_s) - 0.1$		$(+V_s) - 1$	$(-V_s) - 0.1$		$(+V_s) - 1$	V
Common-Mode Rejection Ratio³ DC to 60 Hz with 1 kΩ Source Imbalance								
G = +5 to +1000	$V_s = \pm 5\text{ V}, V_{CM} = -4\text{ V}$ to $+3.0\text{ V}$	77	90		83	96		dB
G = +5 to +1000	$V_s = \pm 15\text{ V}, V_{CM} = -12\text{ V}$ to $+10.9\text{ V}$	77	90		83	96		dB
OUTPUT								
Output Swing	$R_L = 20\text{ k}\Omega$	$(-V_s) + 25$		$(+V_s) - 70$	$(-V_s) + 25$		$(+V_s) - 70$	mV
	$R_L = 100\text{ k}\Omega$	$(-V_s) + 7$		$(+V_s) - 25$	$(-V_s) + 7$		$(+V_s) - 25$	mV
Short-Circuit Current	Short circuit to ground		± 25			± 25		mA

AD627

Parameter	Conditions	AD627A			AD627B			Unit
		Min	Typ	Max	Min	Typ	Max	
DYNAMIC RESPONSE								
Small Signal –3 dB Bandwidth			80		80			kHz
G = +5			3		3			kHz
G = +100			0.4		0.4			kHz
G = +1000			+0.05/–0.06		+0.05/–0.06			V/μs
Slew Rate	V _S = ±5 V, +5 V output step		135		135			μs
Settling Time to 0.01%			350		350			μs
G = +5			330	330				μs
G = +100			560	560				μs
Settling Time to 0.01%	V _S = ±15 V, +15 V output step		330		330			μs
G = +100			560		560			μs
Overload Recovery	50% input overload		3		3			μs

¹ Does not include effects of External Resistor R_G.

² See Table 8 for total RTI errors.

³ See the Using the AD627 section for more information on the input range, gain range, and common-mode range.

DUAL AND SINGLE SUPPLIES

Table 3.

Parameter	Conditions	AD627A			AD627B			Unit
		Min	Typ	Max	Min	Typ	Max	
NOISE								
Voltage Noise, 1 kHz	$Total\ RTI\ Noise = \sqrt{(e_{ni})^2 + (e_{no}/R_G)^2}$		38		38			nV/√Hz
Input, Voltage Noise, e _{ni}			177		177			nV/√Hz
Output, Voltage Noise, e _{no}			1.2		1.2			μV p-p
RTI, 0.1 Hz to 10 Hz			0.56		0.56			μV p-p
G = +5	f = 1 kHz		50		50			fA/√Hz
G = +1000			1.0		1.0			pA p-p
REFERENCE INPUT								
R _{IN}	R _G = ∞		125		125			kΩ
Gain to Output			1		1			
Voltage Range ¹								
POWER SUPPLY								
Operating Range	Dual supply	±1.1		±18	±1.1		±18	V
	Single supply	2.2		36	2.2		36	V
Quiescent Current			60	85		60	85	μA
Over Temperature			200			200		nA/°C
TEMPERATURE RANGE								
For Specified Performance		–40		+85	–40		+85	°C

¹ See Using the AD627 section for more information on the reference terminal, input range, gain range, and common-mode range.

ABSOLUTE MAXIMUM RATINGS

Table 4.

Parameter	Rating
Supply Voltage	$\pm 18\text{ V}$
Internal Power Dissipation ¹	
PDIP (N-8)	1.3 W
SOIC_N (R-8)	0.8 W
-IN, +IN	$-V_S - 20\text{ V}$ to $+V_S + 20\text{ V}$
Common-Mode Input Voltage	$-V_S - 20\text{ V}$ to $+V_S + 20\text{ V}$
Differential Input Voltage (+IN - (-IN))	$+V_S - (-V_S)$
Output Short-Circuit Duration	Indefinite
Storage Temperature Range (N, R)	-65°C to $+125^\circ\text{C}$
Operating Temperature Range	-40°C to $+85^\circ\text{C}$
Lead Temperature (Soldering, 10 sec)	300°C

¹ Specification is for device in free air:
 8-lead PDIP package: $\theta_{JA} = 90^\circ\text{C}/\text{W}$.
 8-lead SOIC_N package: $\theta_{JA} = 155^\circ\text{C}/\text{W}$.

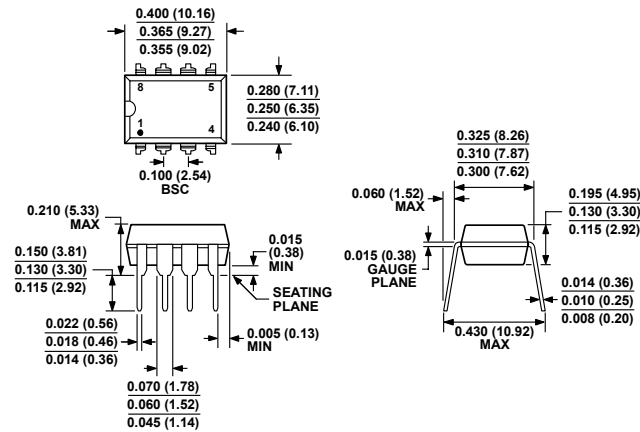
Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



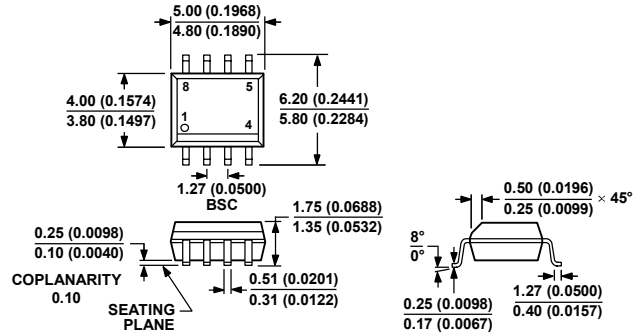
ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-001
CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN. CORNER LEADS MAY BE CONFIGURED AS WHOLE OR HALF LEADS.

Figure 53. 8-Lead Plastic Dual In-Line Package [PDIP] Narrow Body (N-8)
Dimensions shown in inches (and millimeters)



COMPLIANT TO JEDEC STANDARDS MS-012-AA
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 54. 8-Lead Small Standard Outline Package [SOIC_N] Narrow Body (R-8)
Dimensions shown in millimeters (and inches)

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
AD627AN	-40°C to +85°C	8-Lead Plastic Dual In-Line Package [PDIP]	N-8
AD627ANZ ¹	-40°C to +85°C	8-Lead Plastic Dual In-Line Package [PDIP]	N-8
AD627AR	-40°C to +85°C	8-Lead Small Standard Outline [SOIC_N]	R-8
AD627AR-REEL	-40°C to +85°C	8-Lead Small Standard Outline [SOIC_N]	R-8
AD627AR-REEL7	-40°C to +85°C	8-Lead Small Standard Outline [SOIC_N]	R-8
AD627ARZ ¹	-40°C to +85°C	8-Lead Small Standard Outline [SOIC_N]	R-8
AD627ARZ-R7 ¹	-40°C to +85°C	8-Lead Small Standard Outline [SOIC_N]	R-8
AD627ARZ-RL ¹	-40°C to +85°C	8-Lead Small Standard Outline [SOIC_N]	R-8
AD627BN	-40°C to +85°C	8-Lead Plastic Dual In-Line Package [PDIP]	N-8
AD627BNZ ¹	-40°C to +85°C	8-Lead Plastic Dual In-Line Package [PDIP]	N-8
AD627BR	-40°C to +85°C	8-Lead Small Standard Outline [SOIC_N]	R-8
AD627BR-REEL	-40°C to +85°C	8-Lead Small Standard Outline [SOIC_N]	R-8
AD627BR-REEL7	-40°C to +85°C	8-Lead Small Standard Outline [SOIC_N]	R-8
AD627BRZ ¹	-40°C to +85°C	8-Lead Small Standard Outline [SOIC_N]	R-8
AD627BRZ-RL ¹	-40°C to +85°C	8-Lead Small Standard Outline [SOIC_N]	R-8
AD627BRZ-R7 ¹	-40°C to +85°C	8-Lead Small Standard Outline [SOIC_N]	R-8

¹ Z = RoHS Compliant part.